



Continuation of Substance of Interview including description of the general nature of what was discussed: An amendment to claim 12 was proposed by the Examiner to overcome the prior art and clearly stating the invention. One of the key features of the invention is "simultaneously growing at least two Group III nitride semiconductor crystal on the starting substrate" along with other elements that distinguishes the invention from prior art. Based on the conducted search results, the examiner believes that inserting "simultaneously" after 'a step of growing' in line 3 of claim 12 would result the application in condition for allowance. Such proposed amendment was accepted by applicants.